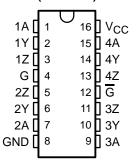
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- Meets or Exceeds the Requirements of TIA/EIA-422-B and ITU Recommendation V 11
- Low Power, I_{CC} = 100 μA Typ
- Operates From a Single 5-V Supply
- High Speed, t_{PLH} = t_{PHL} = 7 ns Typ
- Low Pulse Distortion, t_{sk(p)} = 0.5 ns Typ
- High Output Impedance in Power-Off Conditions
- Improved Replacement for AM26LS31
- Available in Q-Temp Automotive
 - High-Reliability Automotive Applications
 - Configuration Control/Print Support
 - Qualification to Automotive Standards

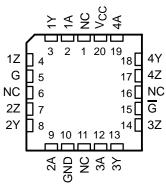
description

The AM26C31 is a differential line driver with complementary outputs, designed to meet the requirements of TIA/EIA-422-B and ITU (formerly CCITT). The 3-state outputs have high-current capability for driving balanced lines, such as twisted-pair or parallel-wire transmission lines, and they provide the high-impedance state in the power-off condition. The enable functions are common to all four drivers and offer the choice of an active-high (G) or active-low (\overline{G}) enable input. BiCMOS circuitry reduces power consumption without sacrificing speed.

AM26C31M . . . J OR W PACKAGE AM26C31C/I/Q . . . D, DB, N, OR NS PACKAGE (TOP VIEW)



AM26C31M . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

The AM26C31C is characterized for operation from 0°C to 70°C, the AM26C31I is characterized for operation from –40°C to 85°C, the AM26C31Q is characterized for operation over the automotive temperature range of –40°C to 125°C, and the AM26C31M is characterized for operation over the full military temperature range of –55°C to 125°C.

AVAILABLE OPTIONS

		PACKAGED DEVICES							
TA	PLASTIC SMALL OUTLINE (D, NS)	PLASTIC SHRINK SMALL OUTLINE (DB)	PLASTIC DIP (N)	CERAMIC CHIP CARRIER (FK)	CERAMIC DIP (J)	CERAMIC DUAL FLATPACK (W)			
0°C to 70°C	AM26C31CD AM26C31CNS	AM26C31CDB —	AM26C31CN —	_	_	_			
-40°C to 85°C	AM26C31ID AM26C31INS	AM26C31IDB —	AM26C31IN —	_	_	_			
–40°C to 125°C	AM26C31QD	AM26C31QDB	AM26C31QN	_	_	_			
−55°C to 125°C	_	_	_	AM26C31MFK	AM26C31MJ	AM26C31MW			

The D package also is available taped and reeled. Add the suffix R to device type (e.g., AM26C31CDR). The DB and NS packages are only available taped and reeled.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

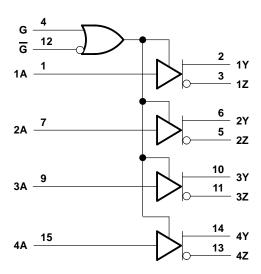


FUNCTION TABLE (each driver)

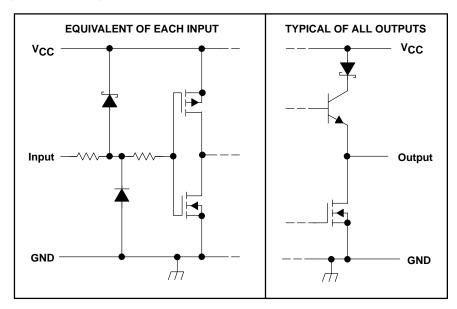
INPUT	ENA	BLES	OUTI	PUTS
Α	G	G	Υ	Z
Н	Н	Х	Н	L
L	Н	X	L	Н
Н	Х	L	Н	L
L	Х	L	L	Н
Х	L	Н	Z	Z

H = High level, L = Low level, X = Irrelevant, Z = High impedance (off)

logic diagram (positive logic)



schematics of inputs and outputs





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

	–0.5 V to 7 V
	0.5 V to V _{CC} + 0.5 V
	±20 mA
	–200 mA
	See Dissipation Rating Table
) package	
OB package	82°C/W
	64°C/W
for 10 seconds	260°C
	—65°C to 150°C
	D package DB package I package IS package for 10 seconds

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values, except differential output voltage (VOD), are with respect to the network ground terminal.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 125°C POWER RATING
FK	1375 mW	11 mW/°C	275 mW
J	1375 mW	11 mW/°C	275 mW
W	1000 mW	8.0 mW/°C	200 mW

recommended operating conditions

				NOM	MAX	UNIT
Vcc	V _{CC} Supply voltage		4.5	5	5.5	V
VID	Differential input voltage			±7		V
VIH	High-level input voltage		2			V
VIL	V _{IL} Low-level input voltage				0.8	V
ІОН	IOH High-level output current				-20	V
loL	I _{OL} Low-level output current				20	V
		AM26C31C	0		70	
l ₋ .	Operating free air temperature	AM26C31I	-40		85	°С
TA	Operating free-air temperature	AM26C31Q	-40		125	C
		AM26C31M	-55		125	



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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CO	ONDITIONS	AM26C31C AM26C31I			UNIT
				MIN	TYP [†]	MAX	
VOH	High-level output voltage	$I_O = -20 \text{ mA}$		2.4	3.4		V
VOL	Low-level output voltage	$I_O = 20 \text{ mA}$			0.2	0.4	V
VOD	Differential output voltage magnitude	$R_L = 100 \Omega$,	See Figure 1	2	3.1		V
$\Delta V_{OD} $	Change in magnitude of differential output voltage‡	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
Voc	Common-mode output voltage	$R_L = 100 \Omega$,	See Figure 1			3	V
Δ VOC	Change in magnitude of common-mode output voltage [‡]	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
lį	Input current	V _I = V _{CC} or GND				±1	μΑ
lo (m	Driver output current with newer off	\/O	V _O = 6 V			100	
IO(off)	Driver output current with power off	VCC = 0	$V_0 = -0.25 \text{ V}$			-100	μΑ
los	Driver output short-circuit current	VO = 0		-30		-150	mA
1	High impedance off state output current	V _O = 2.5 V				20	
loz	High-impedance off-state output current	V _O = 0.5 V			-20	μΑ	
			V _I = 0 V or 5 V			100	μΑ
lcc	C Quiescent supply current I _O = 0	V _I = 2.4 V or 0.5 V, See Note 3		1.5	3	mA	
Ci	Input capacitance				6		pF

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

NOTE 3: This parameter is measured per input. All other inputs are at 0 or 5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		AM26C31C AM26C31I			UNIT
				MIN	TYP [†]	MAX	
tPLH	Propagation delay time, low- to high-level output	S1 is open,	See Figure 2	3	7	12	ns
t _{PHL}	Propagation delay time, high- to low-level output	S1 is open,	See Figure 2	3	7	12	ns
^t sk(p)	Pulse skew time (t _{PLH} - t _{PHL})	S1 is open,	See Figure 2		0.5	4	ns
tr(OD), tf(OD)	Differential output rise and fall times	S1 is open,	See Figure 3		5	10	ns
^t PZH	Output enable time to high level	S1 is closed,	See Figure 4		10	19	ns
tPZL	Output enable time to low level	S1 is closed,	See Figure 4		10	19	ns
^t PHZ	Output disable time from high level	S1 is closed,	See Figure 4		7	16	ns
^t PLZ	Output disable time from low level	S1 is closed,	See Figure 4		7	16	ns
C _{pd}	Power dissipation capacitance (each driver) (see Note 4)	S1 is open,	See Figure 2		170		pF

[†] All typical values are at $V_{CC} = 5 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

NOTE 4: C_{pd} is used to estimate the switching losses according to $P_D = C_{pd} \times V_{CC}^2 \times f$, where f is the switching frequency.



[‡] $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low level.

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electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CO	ONDITIONS	AM26C31Q AM26C31M			UNIT
				MIN	TYP [†]	MAX	
Vон	High-level output voltage	$I_O = -20 \text{ mA}$		2.2	3.4		V
VOL	Low-level output voltage	I _O = 20 mA			0.2	0.4	V
IVODI	Differential output voltage magnitude	$R_L = 100 \Omega$,	See Figure 1	2	3.1		V
Δ V _{OD}	Change in magnitude of differential output voltage‡	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
Voc	Common-mode output voltage	$R_L = 100 \Omega$,	See Figure 1			3	V
Δ VOC	Change in magnitude of common-mode output voltage [‡]	$R_L = 100 \Omega$,	See Figure 1			±0.4	V
lį	Input current	$V_I = V_{CC}$ or GND				±1	μΑ
la con	Driver output current with newer off	V 0	VO = 6 V			100	μA
IO(off)	Driver output current with power off	$V_{CC} = 0$ $V_{O} = -0.25 \text{ V}$				-100	μΑ
los	Driver output short-circuit current	VO = 0				-170	mA
1	High impedance off state output current	V _O = 2.5 V				20	
loz	High-impedance off-state output current	V _O = 0.5 V				-20	μA
		I _O = 0	V _I = 0 V or 5 V			100	μΑ
Icc	Quiescent supply current	IO = 0	V _I = 2.4 V or 0.5 V, See Note 3			3.2	mA
Ci	Input capacitance				6		pF

NOTE 3: This parameter is measured per input. All other inputs are at 0 V or 5 V.

switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS		AM26C31Q AM26C31M			UNIT
				MIN	TYP†	MAX	
tPLH	Propagation delay time, low- to high-level output	S1 is open,	See Figure 2		7	12	ns
tPHL	Propagation delay time, high- to low-level output	S1 is open,	See Figure 2		6.5	12	ns
^t sk(p)	Pulse skew time (tpLH - tpHL)	S1 is open,	See Figure 2		0.5	4	ns
tr(OD), tf(OD)	Differential output rise and fall times	S1 is open,	See Figure 3		5	12	ns
^t PZH	Output enable time to high level	S1 is closed,	See Figure 4		10	19	ns
t _{PZL}	Output enable time to low level	S1 is closed,	See Figure 4		10	19	ns
^t PHZ	Output disable time from high level	S1 is closed,	See Figure 4		7	16	ns
tPLZ	Output disable time from low level	S1 is closed,	See Figure 4		7	16	ns
C _{pd}	Power dissipation capacitance (each driver) (see Note 4)	S1 is open,	See Figure 2		100	·	pF

 $\overline{\dagger}$ All typical values are at V_{CC} = 5 V and T_A = 25°C. NOTE 4: C_{pd} is used to estimate the switching losses according to $P_D = C_{pd} \times V_{CC}^2 \times f$, where f is the switching frequency.



[†] All typical values are at $V_{CC} = 5$ V and $T_A = 25$ °C. ‡ $\Delta |V_{OD}|$ and $\Delta |V_{OC}|$ are the changes in magnitude of V_{OD} and V_{OC} , respectively, that occur when the input is changed from a high level to a low

PARAMETER MEASUREMENT INFORMATION

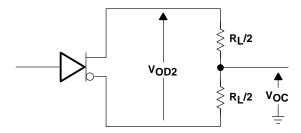
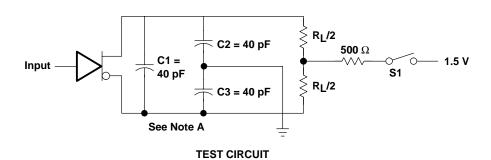
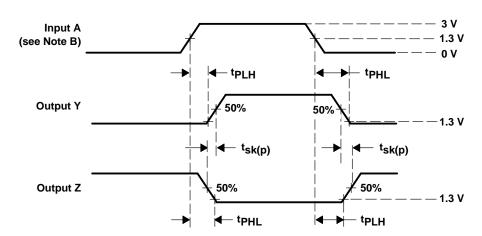


Figure 1. Differential and Common-Mode Output Voltages





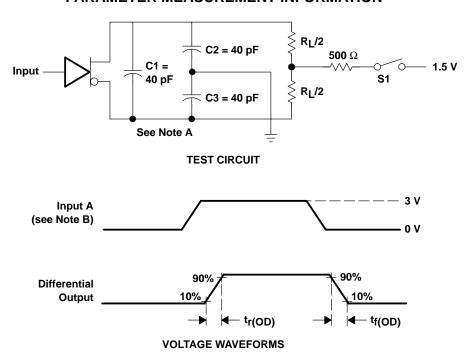
NOTES: A. C1, C2, and C3 include probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, and t_r , $t_f \leq$ 6 ns.

Figure 2. Propagation Delay Time and Skew Waveforms and Test Circuit



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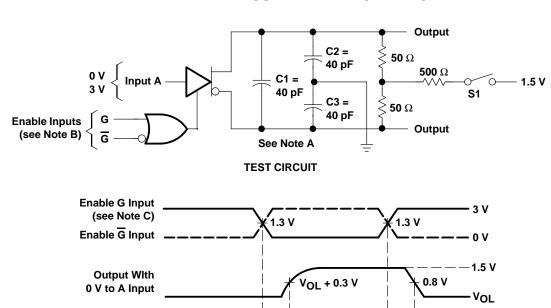


NOTES: A. C1, C2, and C3 include probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, and t_r , $t_f \leq$ 6 ns.

Figure 3. Differential-Output Rise- and Fall-Time Waveforms and Test Circuit

PARAMETER MEASUREMENT INFORMATION



VOLTAGE WAVEFORMS

NOTES: A. C1, C2, and C3 includes probe and jig capacitance.

Output With

3 V to A Input

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, duty cycle \leq 50%, t_{Γ} < 6 ns, and t_{f} < 6 ns.

V_{OH} – 0.3 V

– tPHZ

tPZL

^tPZH

Vон

- 1.5 V

C. Each enable is tested separately.

Figure 4. Output Enable- and Disable-Time Waveforms and Test Circuit



TYPICAL CHARACTERISTICS

SUPPLY CURRENT ٧S **SWITCHING FREQUENCY** 300 250 I_{CC} - Supply Current - mA 200 150 100 T_A = 25°C See Figure 2 50 S1 Open **All Four Channels Switching Simultaneously** N Package 0 0 5 15 20 25 30 35 40 10

Figure 5

f – Switching Frequency – MHz

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